

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HCT240AP,TC74HCT240AF TC74HCT244AP,TC74HCT244AF

Octal Bus Buffer with TTL Input Level

TC74HCT240AP/AF

Inverted, 3-State Outputs

TC74HCT244AP/AF

Non-Inverted, 3-State Outputs

The TC74HCT240A, and HCT244A are high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Their inputs are compatible with TTL, NMOS, and CMOS output voltage levels. The TC74HCT240A is an inverting 3-state buffer having two active-low output enables. The TC74HCT244A is non-inverting 3-state buffer the HCT244A has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 13$ ns (typ.) at V_{CC} = 5 V
- Low power dissipation: $I_{CC} = 4 \ \mu A \ (max)$ at $Ta = 25^{\circ}C$
- Compatible with TTL outputs: $V_{IL} = 0.8 V (max)$

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- Wide interfacing ability: LSTTL, NMOS, CMOS
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: |I_{OH}| = I_{OL} = 6 mA (min)

 $V_{IH} = 2.0 V (min)$

- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2~6 V
- Pin and function compatible with 74LS240/244



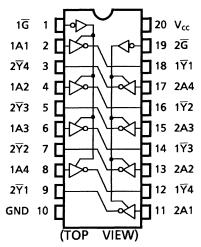
DIP20-P-300-2.54A SOP20-P-300-1.27A

: 1.30 g (typ.) : 0.22 g (typ.)

TOSHIBA

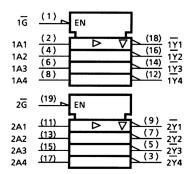
Pin Assignment





IEC Logic Symbol

TC74HCT240A



Truth Table

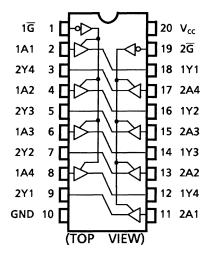
Inp	uts	Outputs				
IG	A _n	Yn	$\overline{Y}_n{}^{\scriptscriptstyle\Delta\!\Delta}$			
L	L	L	Н			
L	Н	Н	L			
Н	Х	Z	Z			

 $\Delta\!\Delta\!$: For TC74HCT240A only

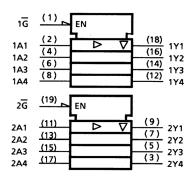
X: Don't care

Z: High impedance

TC74HCT244A



TC74HCT244A



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input diode current	I _{IK}	±20	mA
Output diode current	IOK	±20	mA
DC output current	IOUT	±35	mA
DC V _{CC} /ground current	ICC	±75	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of $Ta = -40 \sim 65^{\circ}$ C. From Ta = 65 to 85° C a derating factor of -10 mW/°C shall be applied until 300 mW.

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5~5.5	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	V _{OUT}	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	t _r , t _f	0~500	ns

Operating Ranges (Note)

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

	Test Condition			Ta = 25°C		Ta = −40~85°C				
Characteristics Symbo				V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
High-level input voltage	V _{IH}	—		4.5~ 5.5	2.0	_	_	2.0	_	V
Low-level input voltage	V _{IL}	_		4.5~ 5.5		_	0.8	_	0.8	V
High-level output	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	4.5	4.4	4.5		4.4		v
voltage			$I_{OH} = -6 \text{ mA}$	4.5	4.18	4.31	—	4.13	—	
Low-level output voltage	V _{OL}	OL VIN = VIH or VIL	I _{OL} = 20 μA	4.5	_	0.0	0.1		0.1	· V
			I _{OL} = 6 mA	4.5	_	0.17	0.26	_	0.33	
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND		5.5	_		±0.5	_	±5.0	μA
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	±0.1	_	±1.0	μA
Quiescent supply current	Icc	$V_{IN} = V_C$	5.5			4.0		40.0	μA	
	IC	Per input: $V_{IN} = 0.5$ V or 2.4 V Other input: V_{CC} or GND		5.5			2.0		2.9	mA

AC Characteristics (input: $t_r = t_f = 6 \text{ ns}$)

		Test Conditio		on		Ta = 25°C			Ta = -40~85°C	
Characteristics Symbo	Symbol		CL (pF)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Output transition time	t _{TLH}		50	4.5	_	7	12	_	15	ns
	t _{THL}			5.5		6	11	—	14	
			50	4.5	_	15	22	—	28	
Propagation delay time	t _{pLH}			5.5		13	20	—	25	ns
(Note 2)	t _{pHL}		150	4.5	_	21	30	—	38	ns
			150	5.5		16	27	—	34	
		_	50	4.5	_	15	25	—	31	- ns
Propagation delay time	t _{pLH}		50	5.5		13	22	—	28	
(Note 3)	t _{pHL}		150	4.5	_	21	33	—	41	
				5.5		18	29	—	37	
		$R_L = 1 \ k\Omega$	50	4.5	_	17	30	—	38	- ns
3-state output enable	t _{pZL}			5.5	_	14	27	—	34	
time	t _{pZH}		150	4.5	_	23	38	—	48	
				5.5	_	20	34	—	43	
3-state output disable	t _{pLZ}	$R_{I} = 1 k\Omega$	50	4.5	_	16	30	—	38	ns
time	t _{pHZ}	NL - 1 N22		5.5	_	13	27	—	34	
Input capacitance	CIN					5	10	—	10	pF
Output capacitance	COUT	—				10	_	—	_	pF
Power dissipation		(Note 2)			33					
capacitance (Note 1)	C _{PD}		1)	Note 3)	_	31	_	_	_	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

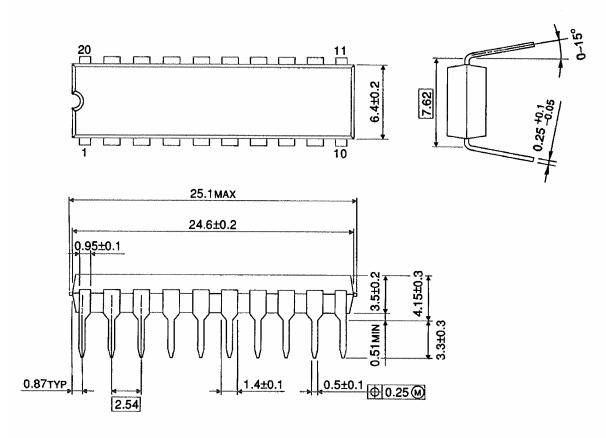
Note 2: TC74HCT240A

Note 3: TC74HCT244A

Package Dimensions

DIP20-P-300-2.54A

Unit : mm



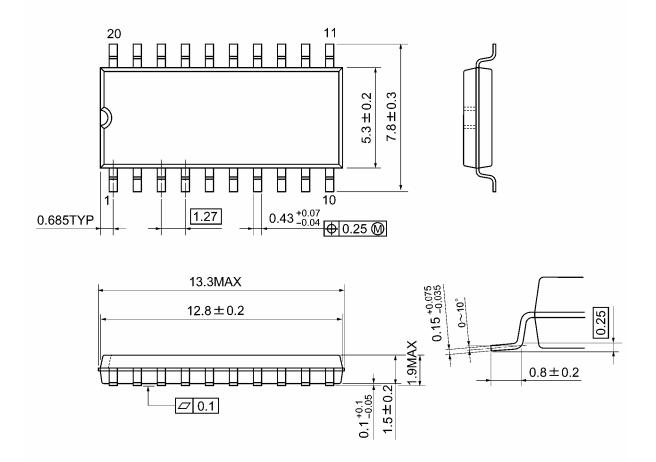
Weight: 1.30 g (typ.)



Package Dimensions

SOP20-P-300-1.27A

Unit: mm



Weight: 0.22 g (typ.)

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20070701-EN GENERAL

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